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Amend D
(NE)

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re Application of

Bojarczuk, et al.

Serial No.: 09/755,164

Group Art Unit: 2826

Filed: January 8, 2001

Examiner: Quinto, Kevin V.

For: ALUMINUM NITRIDE AND ALUMINUM OXIDE/ALUMINUM NITRIDE
HETEROSTRUCTURE GATE DIELECTRIC STACK BASED FIELD EFFECT
TRANSISTORS AND METHOD FOR FORMING SAME

Honorable Commissioner of Patents
Box AF
Alexandria, VA 22313 - 1450

SUPPLEMENTAL AMENDMENT AFTER FINAL REJECTION UNDER 37 C.F.R.
§1.116

Sir:

This paper is a supplement to the Amendment After Final Rejection that was filed on
September 16, 2003 that was responsive to the Office Action dated July 16, 2003. Please amend
the above-identified application as follows:

DO NOT
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INTRODUCTORY COMMENTS

Claims 1-7, 14-18, and 28-31 are all the claims presently pending in the application.

Claims 1, 14-15 and 17 have been amended to more clearly define the invention and claims 28-
31 have been added. Claims 1, 14-15 and 17 are independent.